



Solid State  
Division

# Linear Integrated Circuits

## CA3000

### DC Amplifier

Monolithic Silicon

- Designed for use in Communication, Telemetry, Instrumentation, and Data-Processing Equipment
- Balanced differential-amplifier configuration with controlled constant-current source to provide outstanding versatility
- Built-in temperature stability for operation from -55°C to +125°C
- Companion Application Note, ICAN 5030 "Applications of RCA CA3000 Integrated Circuit DC Amplifier" covers characteristics of different operating modes, frequency considerations, 10 MHz narrow band tuned amplifier design, crystal oscillator design, and many other application aids



#### HIGHLIGHTS

- Input Impedance . . . . . 195 K $\Omega$  typ.
- Voltage Gain. . . . . 30 dB typ.
- Common-Mode Rejection Ratio . . . . . 98 dB typ.
- Input Offset Voltage. . . . . 1.4 mV typ.
- Push-Pull Input and Output
- Frequency Capability  
DC to 30 MHz (with external C and R)
- Wide AGC Range. . . . . 90 dB typ.

#### APPLICATIONS

- Schmitt Trigger
- RC-Coupled Feedback Amplifier
- Mixer
- Comparator
- Modulator
- Crystal Oscillator
- Sense Amplifier

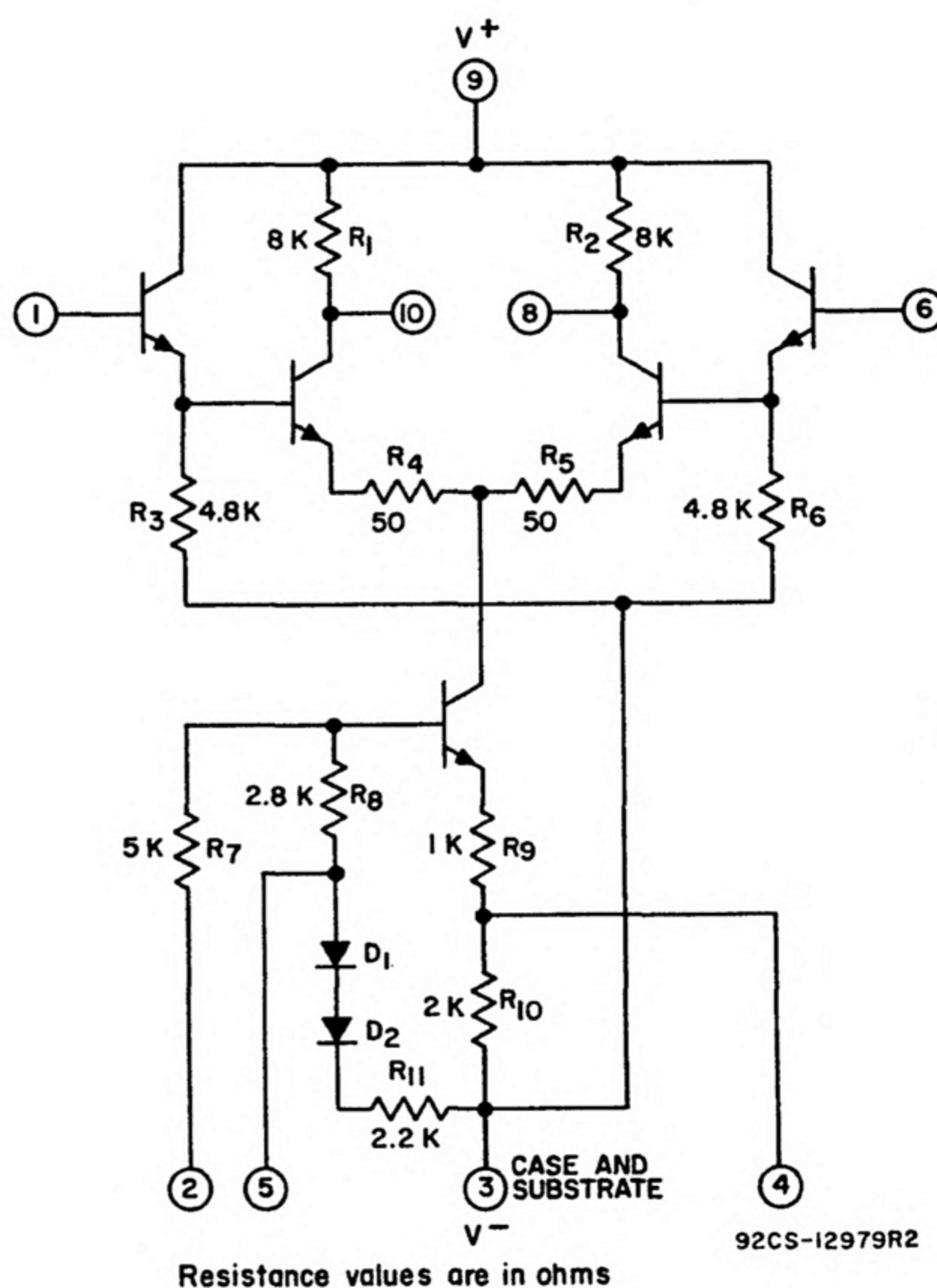


Fig. 1 SCHEMATIC DIAGRAM

**ABSOLUTE-MAXIMUM VOLTAGE LIMITS, at  $T_{FA} = 25^{\circ}C$**

Indicated voltage limits for each terminal can be used under specified voltage conditions for other terminals

All voltages are with respect to ground (common terminal of Positive and Negative DC Supplies)

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
1	-2	+2	2	0
			3	-6
			6	0
			9	+6
2	-8	0	1	0
			3	-8
			6	0
3	-10	0	1	0
			2	0
			6	0
4	-8	0	1	0
			2	0
			6	0
5	-6	0	1	0
			2	0
			3	-6
			6	0
9	+6	0	1	0
			2	0
			3	-6
			6	0

TERMINAL	VOLTAGE LIMITS		CONDITIONS	
	NEGATIVE	POSITIVE	TERMINAL	VOLTAGE
6	-2	+2	1	0
			2	0
			3	-6
			9	+6
7	NO CONNECTION			
8	0	+6	1	0
			2	0
			3	-6
9	0	+10	1	0
			2	0
			3	-6
10	0	+6	1	0
			2	0
			3	-6
CASE	Internally Connected to Terminal No.3 (Substrate) DO NOT GROUND			

OPERATING-TEMPERATURE RANGE . . . . .  $-55^{\circ}C$  to  $+125^{\circ}C$   
 STORAGE-TEMPERATURE RANGE . . . . .  $-65^{\circ}C$  to  $+150^{\circ}C$   
 LEAD-TEMPERATURE (During Soldering):  
 At distance  $1/16 \pm 1/32$  inch ( $1.59 \pm 0.79$  mm)  
 from case for 10 seconds max. . . . .  $+265^{\circ}C$

MAXIMUM SINGLE-ENDED INPUT-SIGNAL VOLTAGE . . .  $\pm 4$  V  
 MAXIMUM COMMON-MODE INPUT-SIGNAL VOLTAGE . . .  $\pm 2$  V  
 MAXIMUM DEVICE DISSIPATION:  
 From  $-55^{\circ}C$  to  $85^{\circ}C$ . . . . . 450 mW  
 Above  $85^{\circ}C$  . . . . . Derate 5 mW/ $^{\circ}C$

[www.datasheetcatalog.com](http://www.datasheetcatalog.com)

**STATIC CHARACTERISTICS AND TEST CIRCUITS FOR TYPE CA3000**

INPUT OFFSET VOLTAGE AND CURRENT vs TEMPERATURE

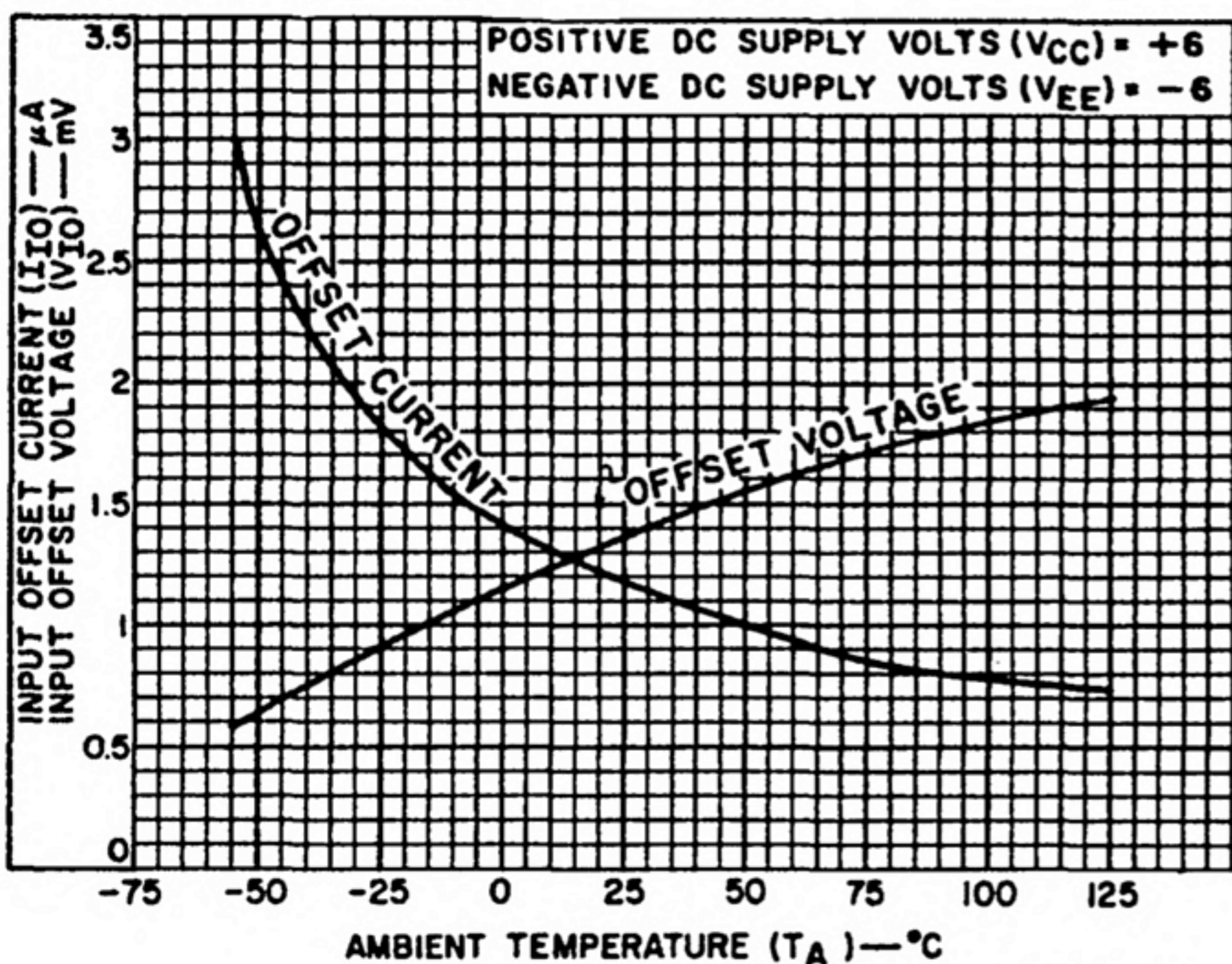


Fig.2

92CS-13299

INPUT BIAS CURRENT vs TEMPERATURE

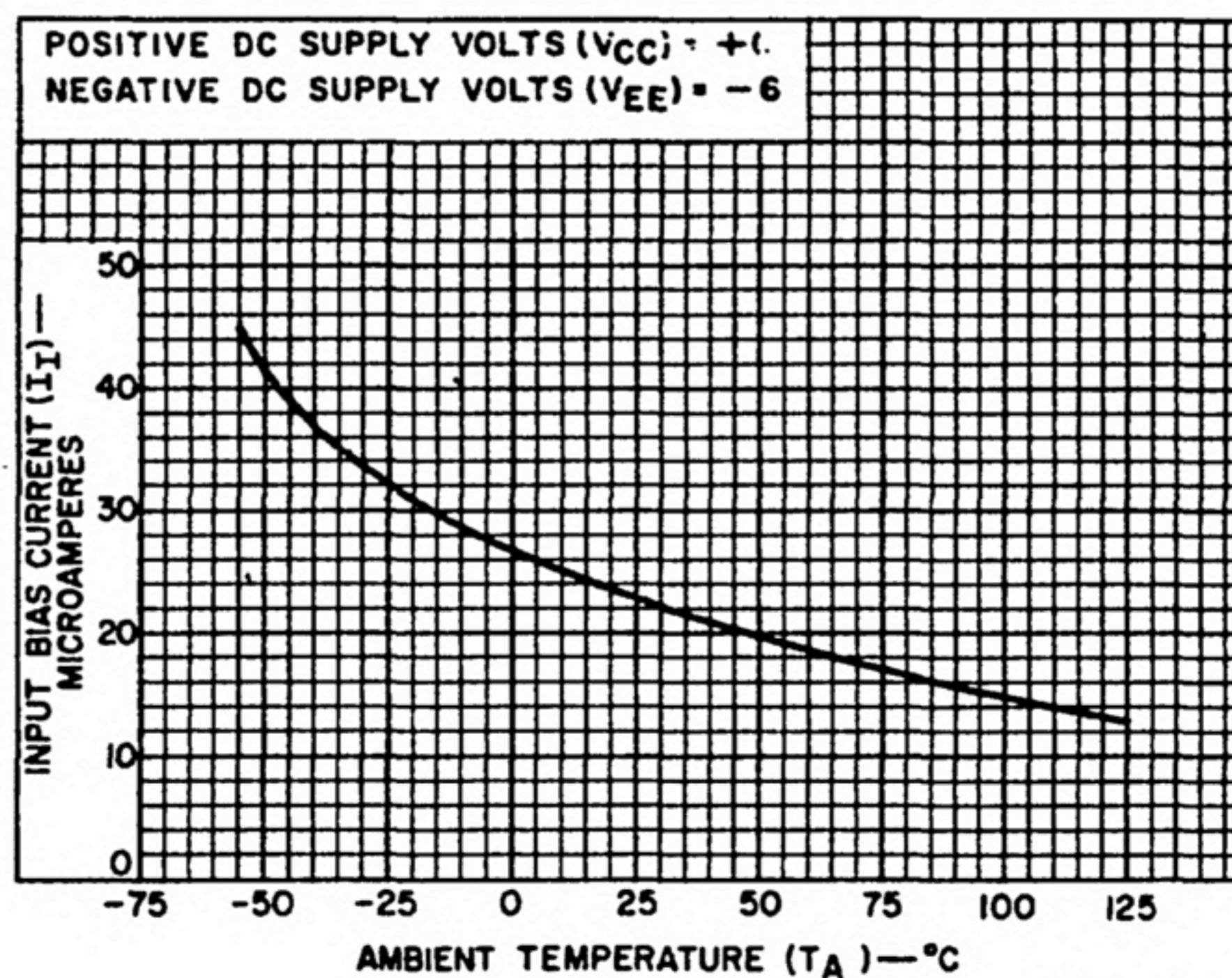


Fig.3

92CS-13296

**ELECTRICAL CHARACTERISTICS**, at  $T_{FA} = 25^{\circ}\text{C}$ ,  $V_{CC} = +6\text{V}$ ,  $V_{EE} = -6\text{V}$ , unless otherwise specified

CHARACTERISTICS	SYMBOLS	SPECIAL TEST CONDITIONS Terminals No.4 & No.5 Not Connected Unless Specified	TEST CIRCUITS	LIMITS					TYPICAL CHARAC- TERISTICS CURVES
				TYPE CA3000					
				Fig.	Min.	Typ.	Max.	Units	Fig.
<b>STATIC CHARACTERISTICS</b>									
Input Offset Voltage	$V_{IO}$			-	1.4	5	mV	2	
Input Offset Current	$I_{JO}$			-	1.2	10	$\mu\text{A}$	2	
Input Bias Current	$I_{IB}$			-	23	36	$\mu\text{A}$	3	
Quiescent Operating Voltage	$V_8$ or $V_{IO}$	TERMINALS							
		4	5						
		NC	NC	-	2.6	-	V	4	
		NC	VEE	-	4.2	-	V	4	
		VEE	NC	-	-1.5	-	V	4	
		VEE	VEE	-	0.6	-	V	4	
Device Dissipation	$P_D$	NC	NC	-	30	-	mW	NONE	
<b>DYNAMIC CHARACTERISTICS</b>									
Differential Voltage Gain Single-Ended Input	$A_{DIFF}$	Single-Ended Output $f = 1 \text{ kHz}$	9	28	32	-	dB	5	
		Double-Ended Output $f = 1 \text{ kHz}$	9	-	38	-	dB	5	
Bandwidth at -3 dB Point	BW	$V_I = 10 \text{ mV}$ , $R_s = 1 \text{ k}\Omega$		-	650	-	kHz	7	
Maximum Output Voltage Swing	$V_{OUT(P-P)}$	$f = 1 \text{ kHz}$	9	-	6.4	-	V(P-P)	NONE	
Common-Mode Rejection Ratio	CMRR	$f = 1 \text{ kHz}$	13	70	98	-	dB	8	
Single-Ended Input Impedance	$Z_{IN}$	$f = 1 \text{ kHz}$	15	70K	195K	-	$\Omega$	10	
Single-Ended Output Impedance	$Z_{OUT}$	$f = 1 \text{ kHz}$	17	5.5K	8K	10.5K	$\Omega$	12	
Total Harmonic Distortion	THD	$R_S = 1 \text{ k}\Omega$ $f = 1 \text{ kHz}$ $V_O = 42 \text{ V}_{p-p}$		-	0.2	5	%	14	
AGC Range (Maximum Voltage Gain to Complete Cutoff)	AGC	$f = 1 \text{ kHz}$	20	80	90	-	dB	NONE	

**QUIESCENT OPERATING VOLTAGE vs TEMPERATURE**

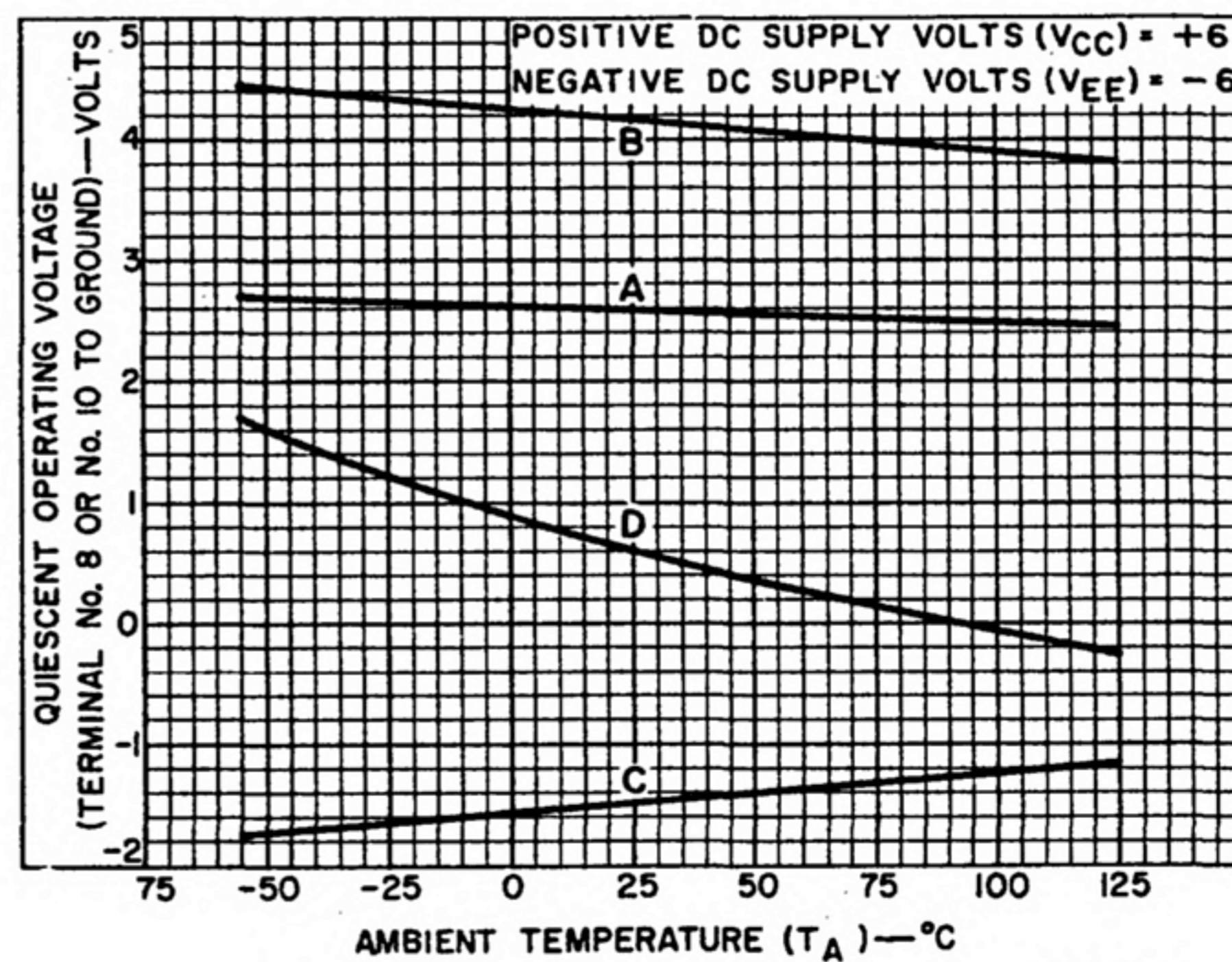


Fig. 4

92CS-13394

DYNAMIC CHARACTERISTICS AND TEST CIRCUIT FOR TYPE CA3000

DIFFERENTIAL VOLTAGE GAIN vs TEMPERATURE

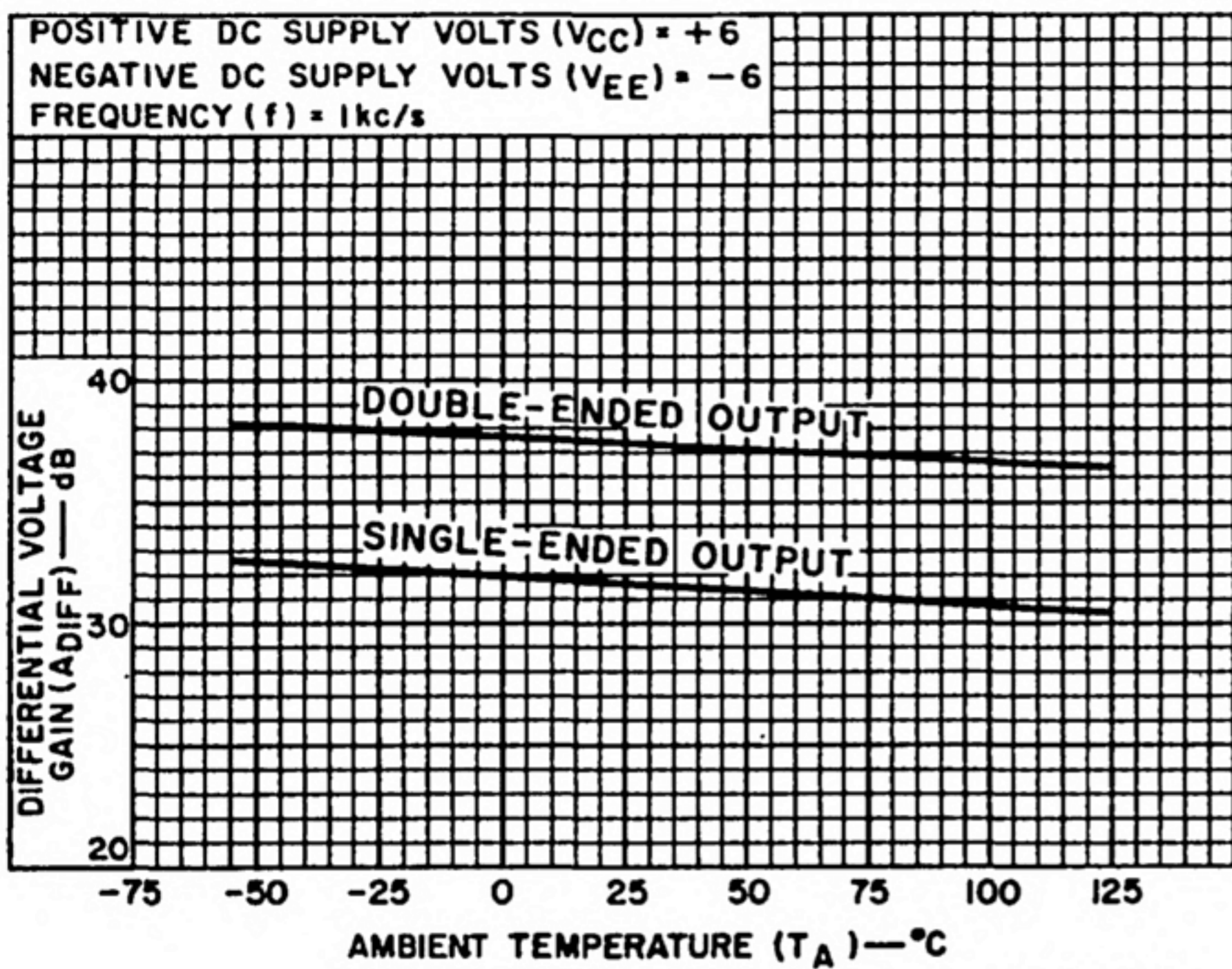


Fig.5

92CS-13594

DIFFERENTIAL VOLTAGE GAIN AND MAXIMUM OUTPUT VOLTAGE SWING TEST CIRCUIT

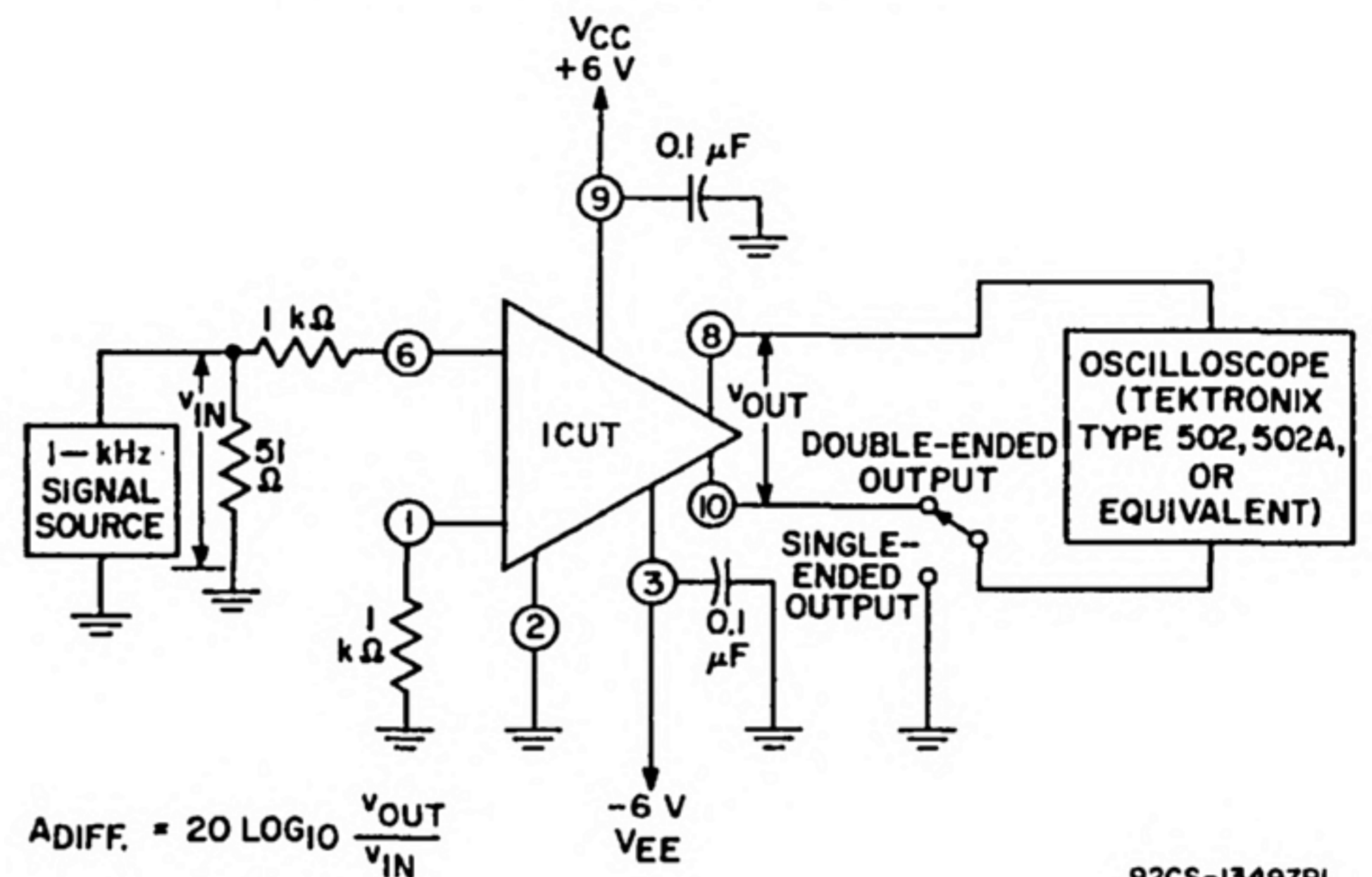


Fig.6

92CS-13497R1

BANDWIDTH AT -3 dB POINT vs TEMPERATURE

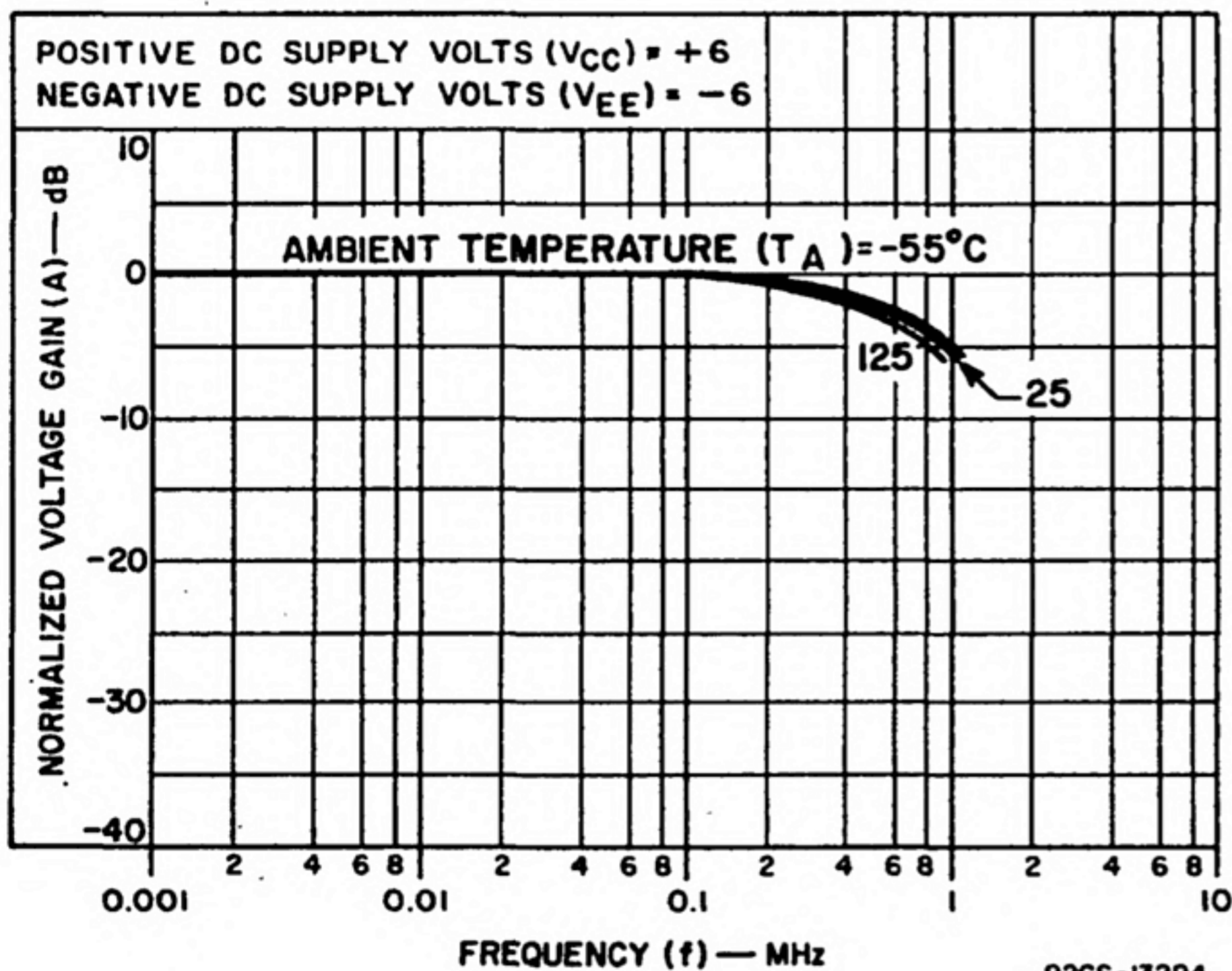


Fig.7

92CS-13294

COMMON-MODE REJECTION RATIO vs TEMPERATURE

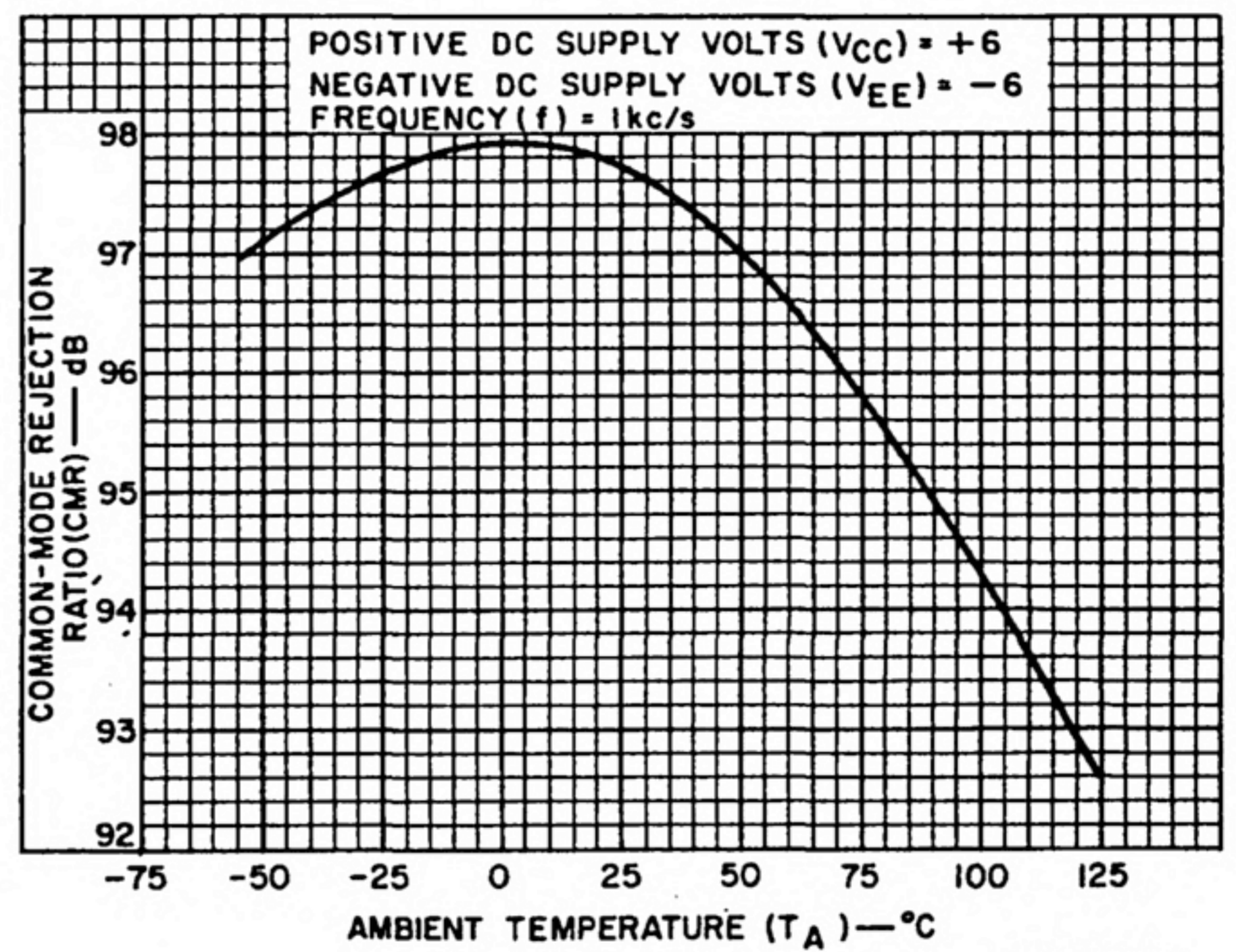


Fig.8

92CS-13297

COMMON-MODE REJECTION RATIO TEST CIRCUIT

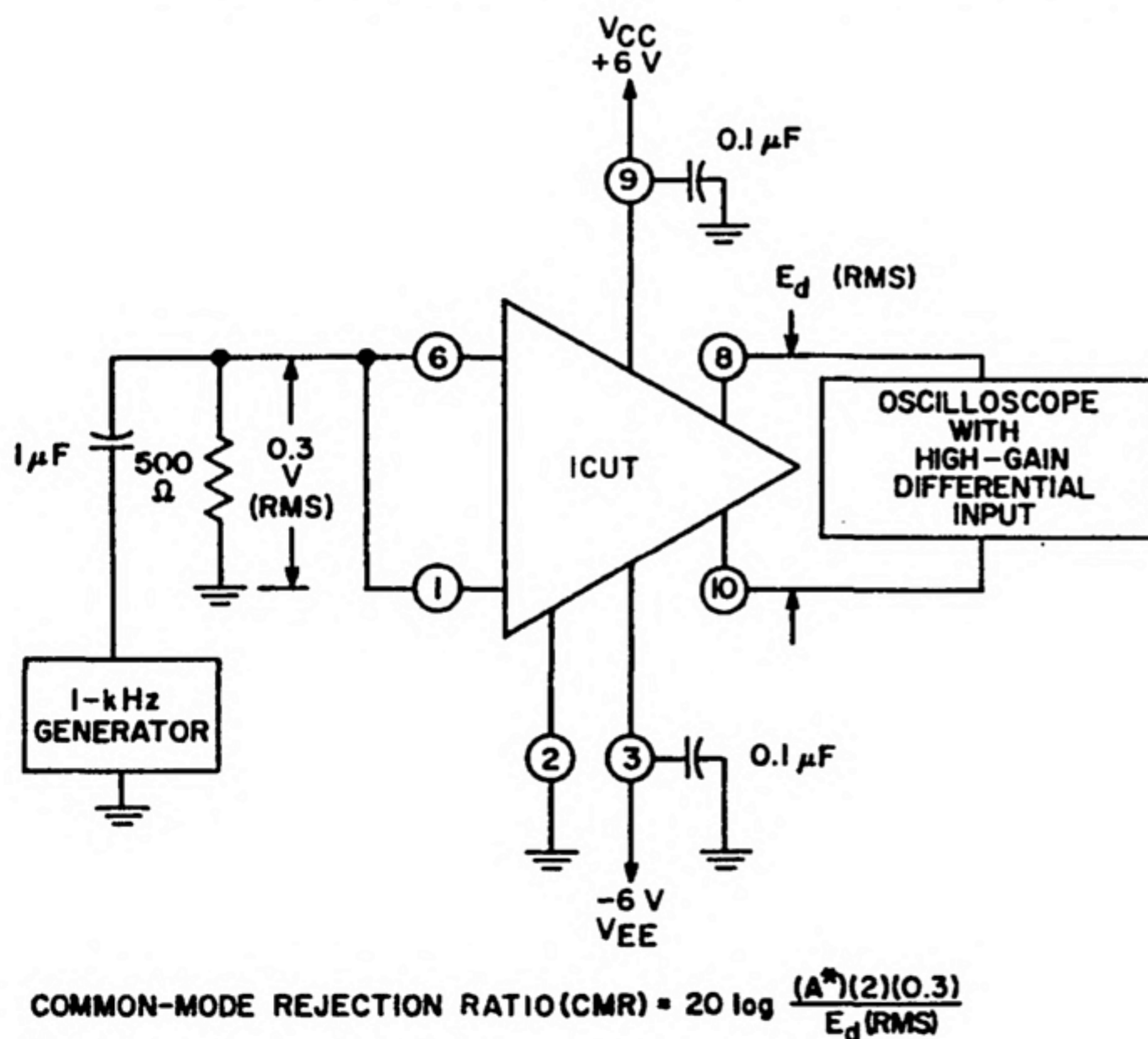


Fig.9

92CS-12983R2

SINGLE-ENDED INPUT IMPEDANCE vs TEMPERATURE

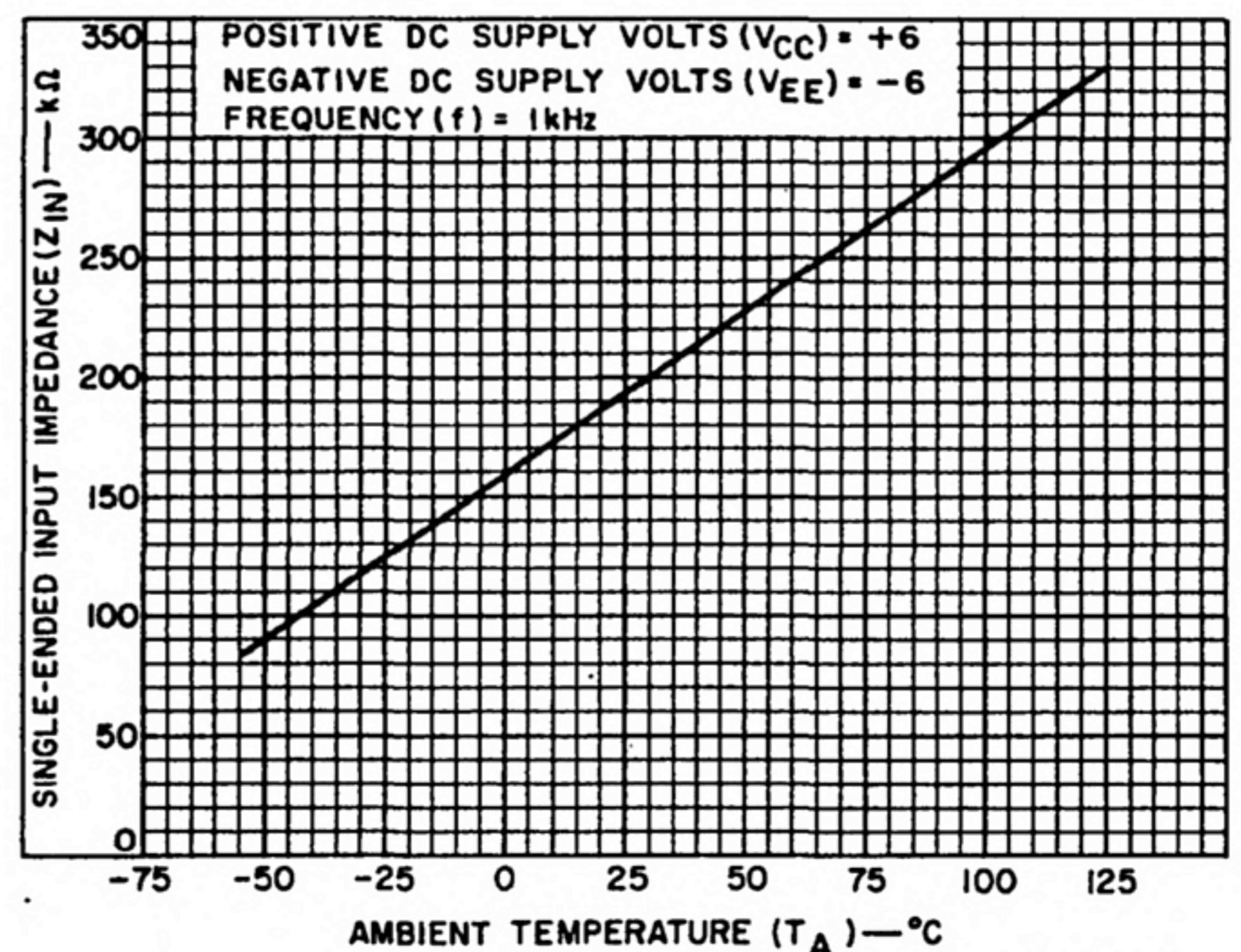


Fig.10

92CS-13298

COMMON-MODE REJECTION RATIO (CMR) = 20 log  $\frac{(A^*)(2)(0.3)}{E_d (RMS)}$

\*A = SINGLE-ENDED VOLTAGE GAIN AS MEASURED IN CIRCUIT SHOWN IN FIG. 6B

DYNAMIC CHARACTERISTICS AND TEST CIRCUITS FOR TYPE CA3000

SINGLE-ENDED INPUT IMPEDANCE TEST CIRCUIT

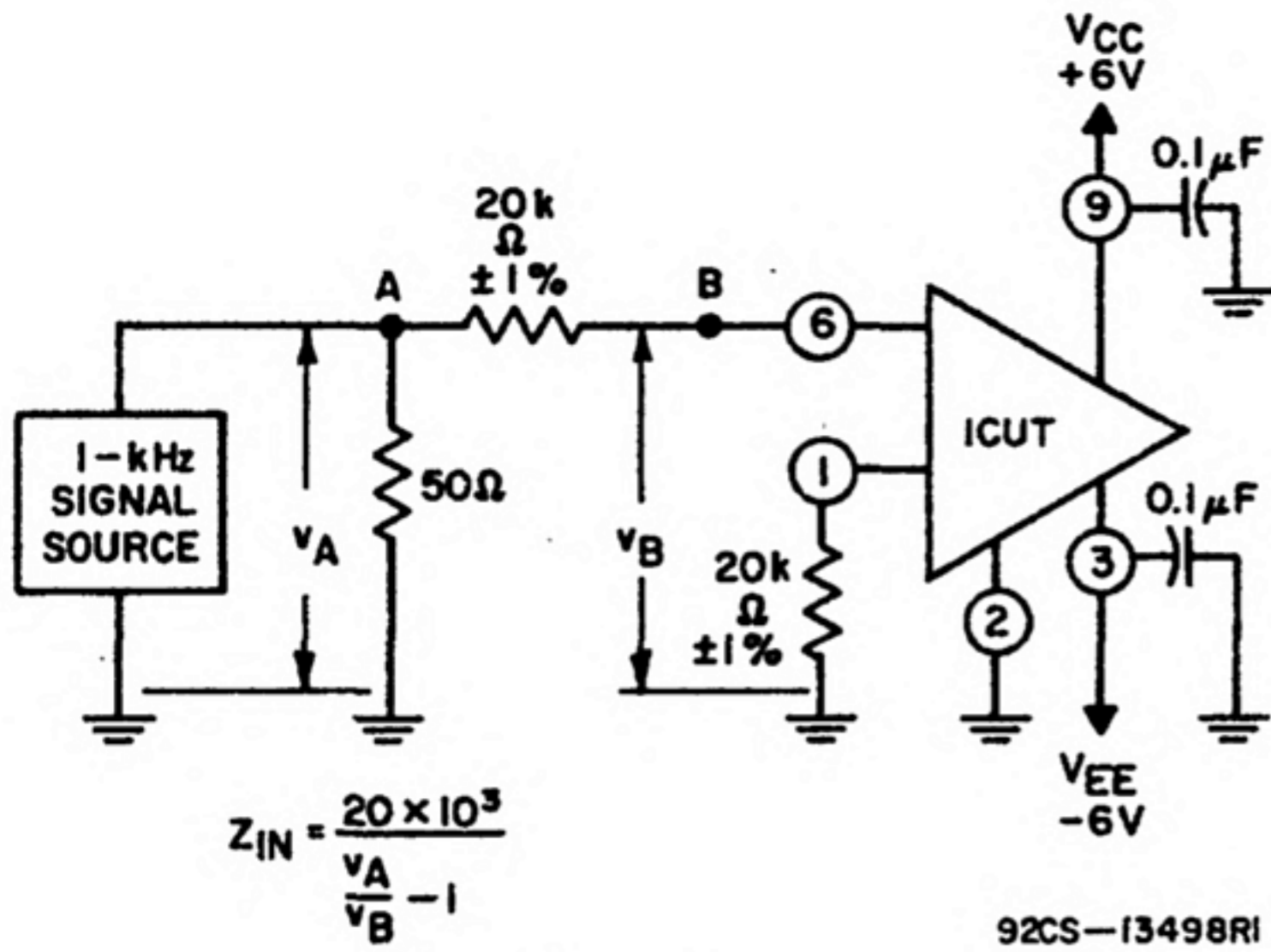


Fig. 11

SINGLE-ENDED OUTPUT IMPEDANCE vs TEMPERATURE

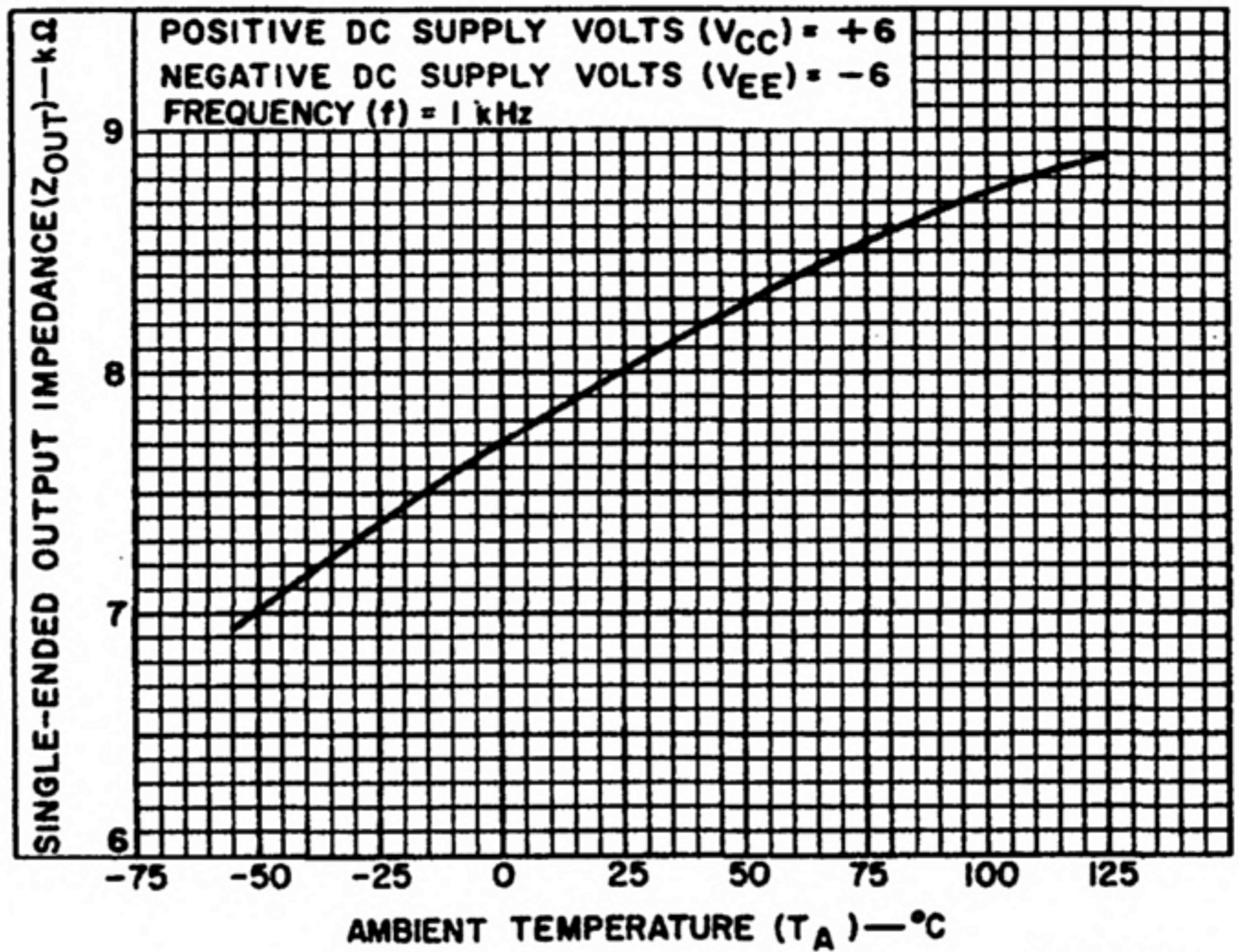


Fig. 12

SINGLE-ENDED OUTPUT IMPEDANCE TEST CIRCUIT

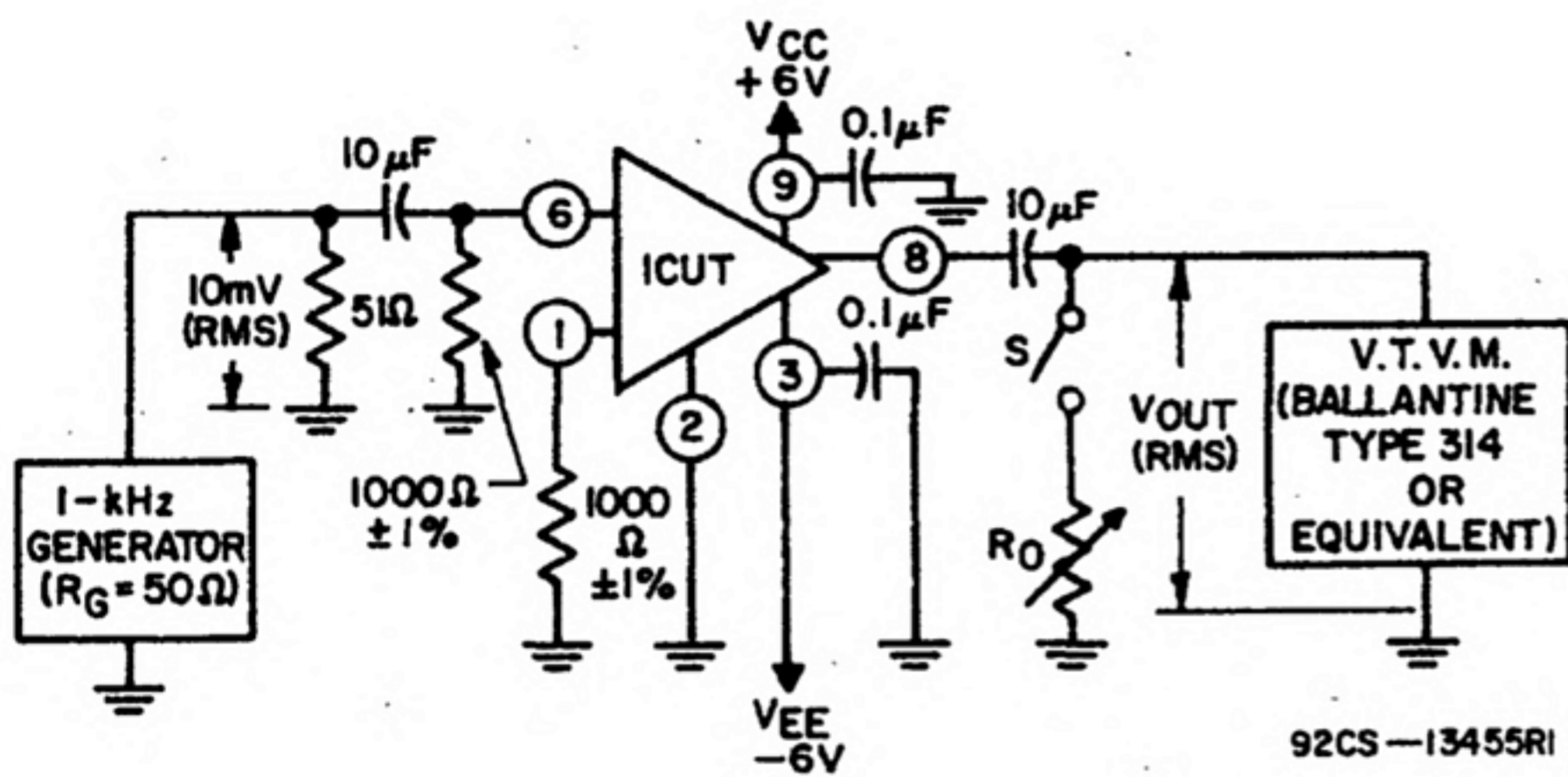


Fig. 13

TOTAL HARMONIC DISTORTION vs TEMPERATURE

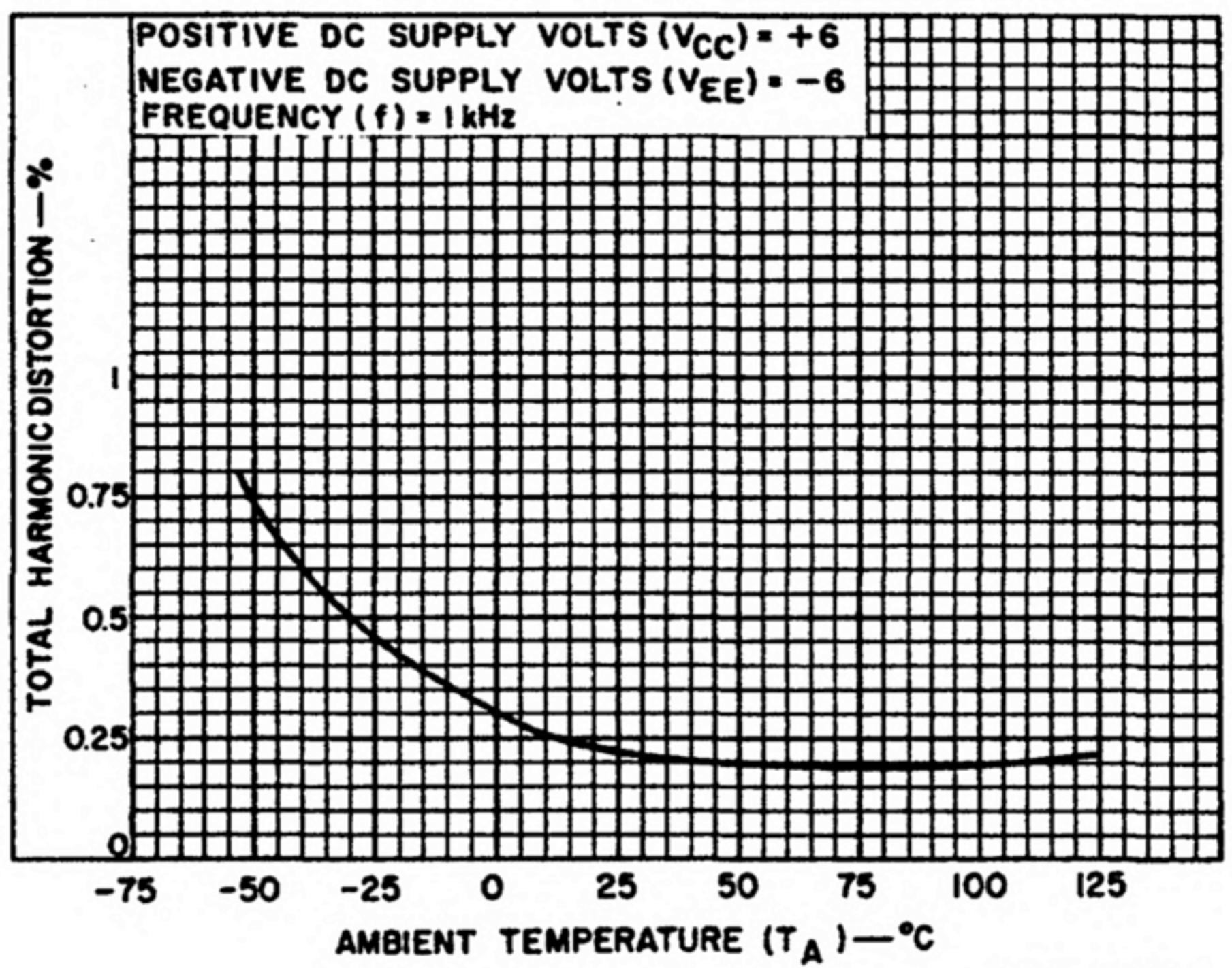


Fig. 14

AGC RANGE TEST CIRCUIT

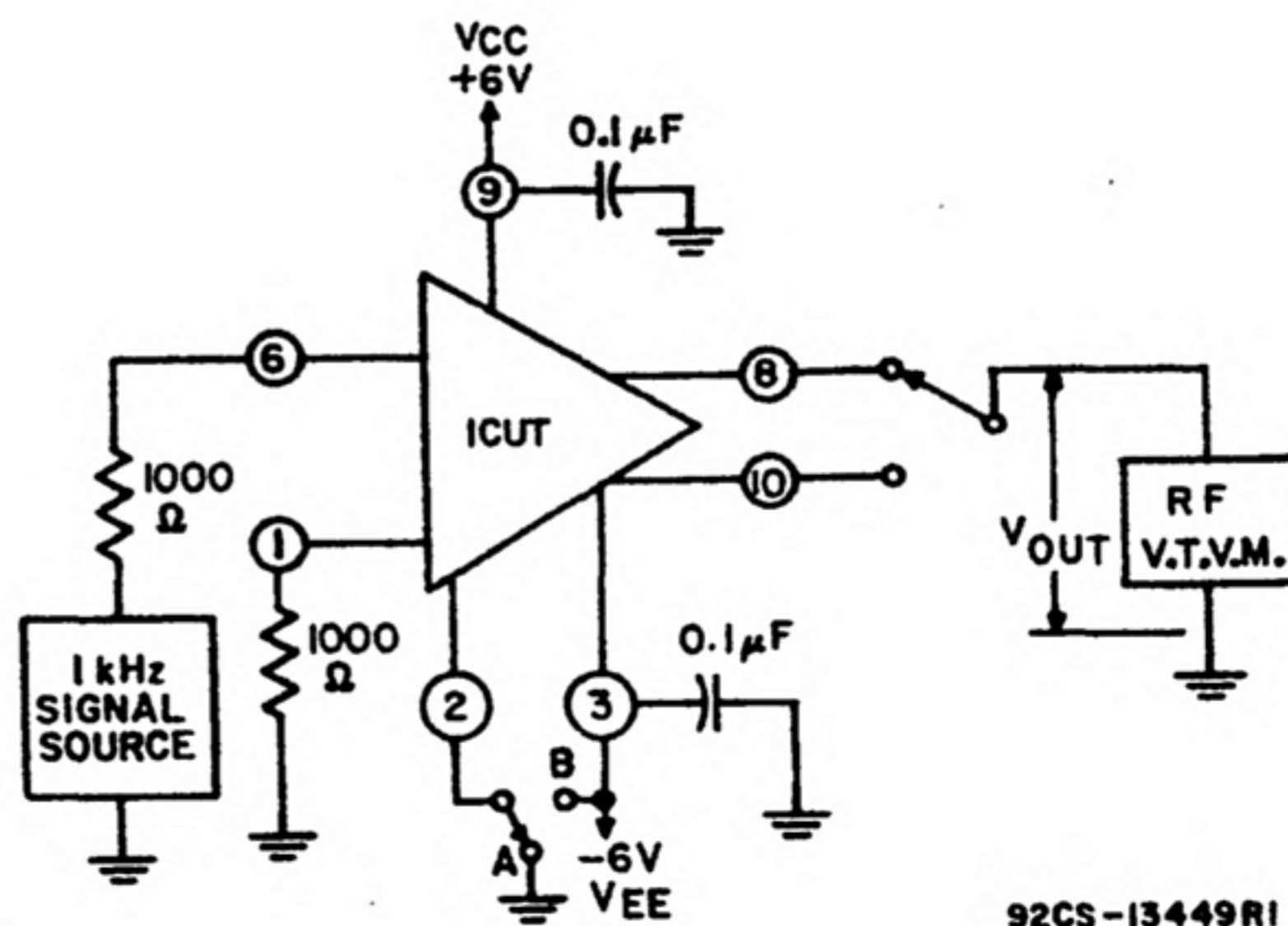


Fig. 15